

### **isc** Silicon NPN Darlington Power Transistor

# 2SD972

#### DESCRIPTION

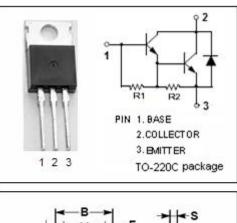
- Collector-Emitter Breakdown Voltage-
- : V<sub>(BR)CEO</sub> = 50V(Min)
- High DC Current Gain
- High Switching Speed
- Wide Area of Safe Operation
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

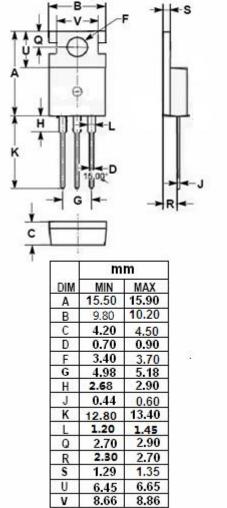
#### APPLICATIONS

Designed for hammer drivers, audio amplifiers applications

### ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT
V <sub>CBO</sub>	Collector-Base Voltage	50	V
V <sub>CEO</sub>	Collector-Emitter Voltage	50	V
VEBO	Emitter-Base Voltage	6	V
Ic	Collector Current-Continuous	4	A
I <sub>CP</sub>	Collector Current-Peak	6	А
IB	Base Current	0.2	А
Pc	Collector Power Dissipation @Tc=25°C	30	W
Tj	Junction Temperature	150	°C
T <sub>stg</sub>	Storage Temperature Range	-55~150	°C





### isc website: <u>www.iscsemi.com</u>



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#### **ELECTRICAL CHARACTERISTICS**

#### $T_c=25^{\circ}C$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	МАХ	UNIT
Vceo(sus)	Collector-Emitter Sustaining Voltage	Ic= 30mA ;I <sub>B</sub> = 0	50			v
V <sub>CE(sat)-1</sub>	Collector-Emitter Saturation Voltage	I <sub>C</sub> = 2A; I <sub>B</sub> = 8mA			1.8	V
V <sub>CE(sat)-2</sub>	Collector-Emitter Saturation Voltage	I <sub>C</sub> = 4A; I <sub>B</sub> = 40mA			2.5	v
V <sub>BE(sat)-1</sub>	Base-Emitter Saturation Voltage	I <sub>C</sub> = 2A; I <sub>B</sub> = 8mA			2.2	v
V <sub>BE(sat)-2</sub>	Base-Emitter Saturation Voltage	I <sub>C</sub> = 4A; I <sub>B</sub> = 40mA			3.0	V
Ісво	Collector Cutoff Current	V <sub>CB</sub> = 50V;I <sub>E</sub> = 0			0.1	mA
I <sub>CEO</sub>	Collector Cutoff Current	V <sub>CE</sub> = 50V; I <sub>B</sub> = 0			0.5	mA
I <sub>EBO</sub>	Emitter Cutoff Current	V <sub>EB</sub> = 5V; I <sub>C</sub> = 0			5	mA
h <sub>FE-1</sub>	DC Current Gain	I <sub>C</sub> = 1A ; V <sub>CE</sub> = 4V	2000			
h <sub>FE-2</sub>	DC Current Gain	I <sub>C</sub> = 3A ; V <sub>CE</sub> = 4V	1000		20000	

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